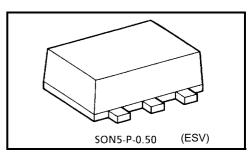
TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7SZ126AFE

Dual Bus Buffer 3-State Output

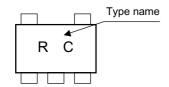
Features

- High output drive: ±24 mA (min) @VCC = 3 V
- Super high speed operation: tpd 2.6 ns (typ.) @VCC = 5 V, 50 pF
- Operation voltage range: $V_{CC (opr)} = 1.8 \sim 5.5 \text{ V}$
- Latch-up performance: ±500 mA or more
- ESD performance: ±200 V or more (JEITA) ±2000 V or more (MIL)
- Power down protection is provided on all inputs and outputs.
- Matches the performance of TC74LCX series when operated at 3.3 V VCC.

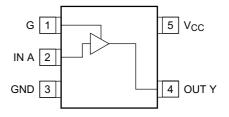


Weight: 0.003 g (typ.)

Marking



Pin Assignment (top view)



Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	-0.5~6	V
DC input voltage	V _{IN}	-0.5~6	V
DC output voltage	V _{OUT}	-0.5~V _{CC} + 0.5	V
Input diode current	I _{IK}	-20	mA
Output diode current	I _{OK}	±20	mA
DC output current	lout	±50	mA
DC V _{CC} /ground current	I _{CC}	±50	mA
Power dissipation	P _D	150	mW
Storage temperature	T _{stg}	-65~150	°C
Lead temperature (10s)	T_L	260	°C

Truth Table

А	G	Υ
Х	L	Z
L	Н	L
Н	Н	Н

Logic Diagram



Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	1.8~5.5	V
Supply voltage	VCC	1.5~5.5 (Note)	V
Input voltage	V _{IN}	0~5.5	V
Output voltage	V _{OUT}	0~V _{CC}	V
Operating temperature	T _{opr}	-40~85	°C
		$0\sim20 \ (V_{CC} = 1.8 \ V, \ 2.5 \ V \pm 0.2 \ V)$	ns/V
Input rise and fall time	dt/dv	$0\sim10 \ (V_{CC}=3.3 \ V\pm0.3 \ V)$	
		$0~5~(V_{CC} = 5.5~V \pm 0.5~V)$	

Note: Data retention only

Electrical Characteristics

DC Characteristics

Characteristics Symbol		Cumbal	Test Condition			Ta = 25°C			Ta = -40~85°C		Unit
		V _{CC} (V)		Min	Тур.	Max	Min	Max	Unit		
					1.8	0.75 × V _{CC}		_	0.75 × V _{CC}	_	·
Input voltage	High level V _{IH}		_		2.3~5.5	0.7 × V _{CC}	_	_	0.7 × V _{CC}	_	
Input voltage				1.8	_	_	0.25 × V _{CC}	_	0.25 × V _{CC}		
	Low level	V _{IL}	_		2.3~5.5	_	—	0.3 × V _{CC}	_	0.3 × V _{CC}	
					1.8	1.7	1.8	_	1.7	_	
				100	2.3	2.2	2.3	_	2.2	_	
				$I_{OH} = -100 \mu A$	3.0	2.9	3.0	_	2.9	_	
	High level	\/ - · ·	V _{IN} = V _{IH} or V _{IL}		4.5	4.4	4.5	_	4.4	_	
	nign ievei	Voн		$I_{OH} = -8 \text{ mA}$	2.3	1.9	2.15	_	1.9	_	
				$I_{OH} = -16 \text{ mA}$	3.0	2.4	2.8	_	2.4	_	
Outsut vallesse				$I_{OH} = -24 \text{ mA}$	3.0	2.3	2.68	_	2.3	_	
		•	$I_{OH} = -32 \text{ mA}$	4.5	3.8	4.2	_	3.8	_	V	
Output voltage			$V_{IN} = V_{IH}$	I _{OL} = 100 μA	1.8	_	0	0.1	_	0.1	
					2.3	_	0	0.1	_	0.1	
					3.0	_	0	0.1	_	0.1	
	Low level	V			4.5	_	0	0.1	_	0.1	
Low level	Low level	V _{OL}		I _{OL} = 8 mA	2.3	_	0.1	0.3	_	0.3	
				I _{OL} = 16 mA	3.0	_	0.15	0.4	_	0.4	
				I _{OL} = 24 mA	3.0	_	0.22	0.55	_	0.55	
			$I_{OL} = 32 \text{ mA}$	4.5	_	0.22	0.55	_	0.55		
Input leakage curre	ent	I _{IN}	V _{IN} = 5.5 V or GND		0~5.5	_	_	±1	_	±10	μΑ
3-state output off-s	tate current	l _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL},$ $V_{OUT} = 0 \sim 5.5 \text{ V}$		1.8~5.5			±1	_	±10	μΑ
Power off leakage	current	I _{OFF}	V _{IN} or V _{OUT} = 5.5 V		0.0			1		10	μΑ
Quiescent supply of	current	Icc	V _{IN} = 5.5 V or GND		5.5	_	_	2	_	20	μΑ

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AC Characteristics (unless otherwise specified, Input: $t_r = t_f = 3$ ns)

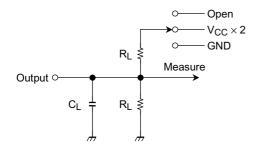
Characteristics	Cumbal	Test Condition		Ta = 25°C		Ta = -40~85°C		- Unit	
Characteristics Symbol		V _{CC} (Min	Тур.	Max	Min	Max	Unit
			1.8	2.0	5.3	11.0	2.0	11.5	
		$C_L = 15 \text{ pF}, R_L = 1 \text{ M}\Omega$	2.5 ± 0.2	8.0	3.4	7.5	0.8	8.0	
Propagation delay time	t _{pLH}		3.3 ± 0.3	0.5	2.5	5.2	0.5	5.5	
Tropagation delay time	t _{pHL}		5.0 ± 0.5	0.5	2.1	4.5	0.5	4.8	
		$C_L = 50 \text{ pF}, R_L = 500 \Omega$	3.3 ± 0.3	1.5	3.2	5.7	1.5	6.0	
		CL = 50 pr, RL = 500 \(\Omega \)	5.0 ± 0.5	0.8	2.6	5.0	0.8	5.3	
		$C_L = 50 \text{ pF}, R_L = 500 \Omega$	1.8	2.0	6.5	11.5	2.0	12.0	ns
Output enable time t _{pZH}	t _{pZH}		2.5 ± 0.2	1.5	3.8	8.0	1.5	8.5	-
	t_{pZL}	OL = 30 pr , RL = 300 \$2	3.3 ± 0.3	1.5	3.2	5.7	1.5	6.0	
			5.0 ± 0.5	0.8	2.3	5.0	0.8	5.3	
Output disable time t _{pLZ}		1.8	2.0	5.6	11.0	2.0	12.0		
	t_{pLZ}	$C_L = 50 \text{ pr}, R_L = 500 \Omega$	2.5 ± 0.2	1.0	4.0	8.0	1.5	8.5	
	t _{pHZ}		3.3 ± 0.3	1.0	3.5	5.7	1.0	6.0	
			5.0 ± 0.5	0.5	2.7	4.7	0.5	5.0	
Input capacitance	C _{IN}	_	0~5.5	_	4				pF
Power dissipation	C _{PD}	(Note)	3.3	_	20	_	_	_	- pF
capacitance	OPD	(Note)	5.5	_	27	_		_	

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

AC Characteristics Measurement Circuit

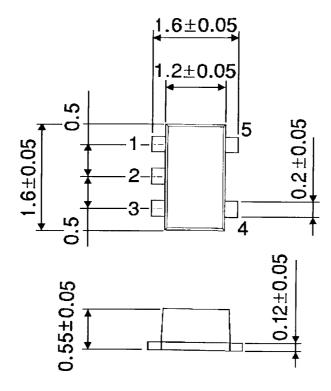


Characteristics	Switch
t _{pLH} , t _{pHL}	Open
t _{pLZ} , t _{pZL}	$V_{CC} \times 2$
t _{pHZ} , t _{pZH}	GND

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Package Dimensions

SON5-P-0.50 Unit: mm



Weight: 0.003 g (typ.)

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000707EBA

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